

Circuit level design and test for the MIL-STD-461 200V/m RS103 and the DO-160 radiated susceptibility test at 200V/m

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1 introduction.

For Army , Navy and Airforce military equipment and DO-160 commercial aircraft avionics radiated susceptibility test levels as high as 200V/m may be specified.

As always it is better to design immunity to the test levels into equipment than to wait until equipment is completed and then perform tests.

This article assumes the worst case qualification test levels of 200V/m

If the radiated susceptibility test levels are lower then all of the predicted circuit test levels can be reduced accordingly.

This article shows levels induced into the circuits when 200V/m is incident on the equipments shielded or unshielded cables. With this information circuits can be designed to be immune the level s
The high level tests require high power amplifiers and antennas capable of coping with the power. Although common in test labs these are not so common in manufacturers test facilities. The circuit level tests describe here require only signal generators or low power amplifiers with a spectrum analyzer or oscilloscope.

Military equipment and Avionic equipment are typically enclosed in well shielded enclosures and the coupling from an incident E field is predominantly to cables at 1GHz and at lower frequencies.

For this reason this report concentrates on cable coupling.

2 Analyzing the circuit test levels.

The Methods of Moments (MOM) formulation was used to model the RS103 and the DO-160 test set up. A ground plane 4m long by 2m wide constructed of numerous patches with the patch maximum dimension limited to 0.3λ .

. Either a single conductor or two conductors 3m long in were constructed at a height of 5cm above the ground plane.

The single conductor was located 10cm from the front of the ground plane. The second conductor was placed a few mm apart from the first. The single conductor was terminated in a S/C representing the connection of a shielded cable to the ground plane. One conductor of the twin conductor cable was terminated in either a short circuit, or a 50 Ohm or 1000 Ohm load and the second to the ground plane.

With the asymmetrical connection of the cable/s (connected to ground plane at one end only) the MOM calculation has been proven to be correct (reference 1). However with the symmetrical connection the MOM fails. This is not a problem as the load current and maximum cable currents are the same as the asymmetrical connection only the resonant frequencies change.

For example for the asymmetrical connection these frequencies are: 25MHz, 75MHz, 125MHz, 225MHz, 275MHz, 325MHz, 375MHz,425MHz--- 975MHz and for the symmetrical connection 50MHz, 150MHz,

250MHz,350MHz, 450MHz, 550MHz, 650MHz, 750MHz, 850MHz --- 1950MHz.

The MOM program used was 4NEC2D by Arie Voors.

Figure 1 shows the model for a single conductor at low frequency and figure 2 at 975MHz.

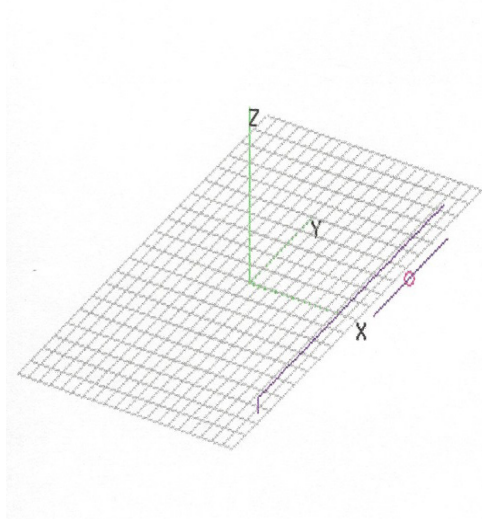


Figure 1 MOM RS103 test set up low frequency.

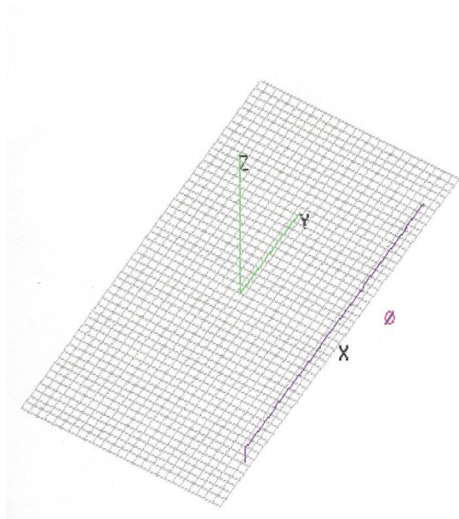


Figure 2 MOM RS103 test set up at 975MHz.

The 4NEC2D program was used to predict the E field at the center of the

conductor and 0.5m above the ground plane. Also the current down the conductor and in the termination of the conductor to the ground plane. Based on the ratio of the 200V/m and the MOM predicted E field the cable and termination currents have been corrected for 200V/m.

Figure 1 shows the S/C termination current and Figure 2 the cable current.

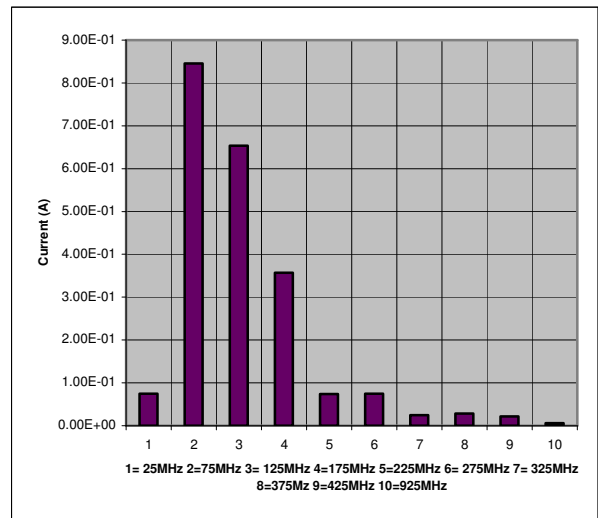


Figure 1 Current in S/C load

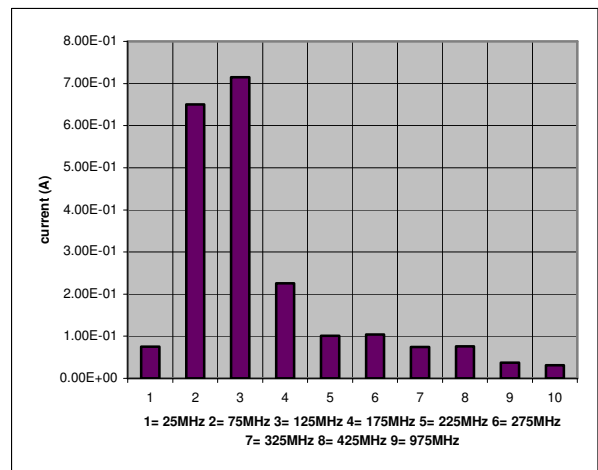


Figure 2 Current down cable with S/C load

The cable current and voltage induced into a two conductor line, where one line is terminated to the ground plane and the second line terminated in either 50 Ohm or 1000 Ohm, was computed. This represents an unshielded signal or control line with 50 Ohm or 1000 Ohm C/M impedance or the input impedance for signals with the return referenced to chassis.

The voltages developed across 50 Ohm for the 200V/m incident E field is shown in Figure 3 and for 1000 Ohm in figure 4.

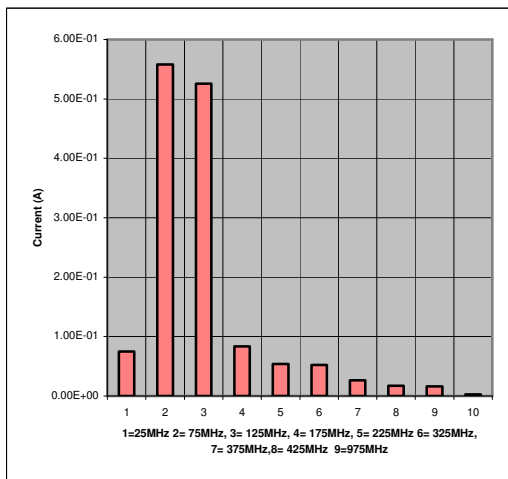


Figure 3 Voltages developed across 50 Ohm load.

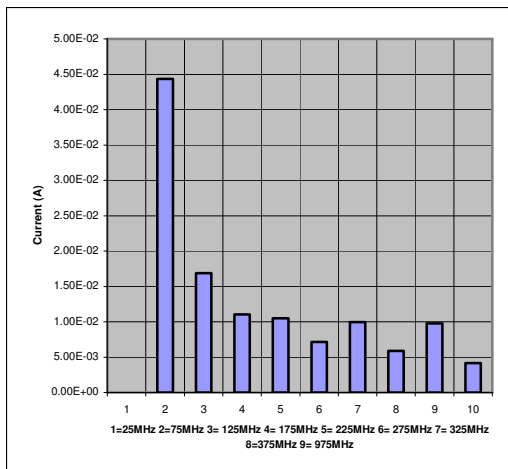


Figure 4 Voltages developed across 1000 Ohm load

Table 1 shows also shows the voltages.

Frequency (MHz)	Voltage across 50 Ohm (V)	Voltage across a1000 Ohm (mV)
25	3.75	29
75	27.9	2200
125	26.3	844
175	4.17	553
225	2.7	525
275	2.6	358
325	1.31	497
375	0.87	294
425	0.8	489
975	0.13	208

Table 1 Voltages developed across a 50 Ohm and 1000 Ohm load.

Clearly for many signal interfaces a signal line filter will be required. Reference 1 describes the design and implementation of a large number of such filters.

Voltage developed into a shielded cable at 200V/m

As current flows down a shielded cable a transferred voltage is developed on the center conductor/s. The voltage is developed across the transfer impedance of the cable.

Two common cables used in military and Avionic equipment is a single braid with high optical coverage and a double braid with high optical coverage.

Assuming the cable shield is terminated at one end to the ground plane the cable current will be that shown in figure 5.

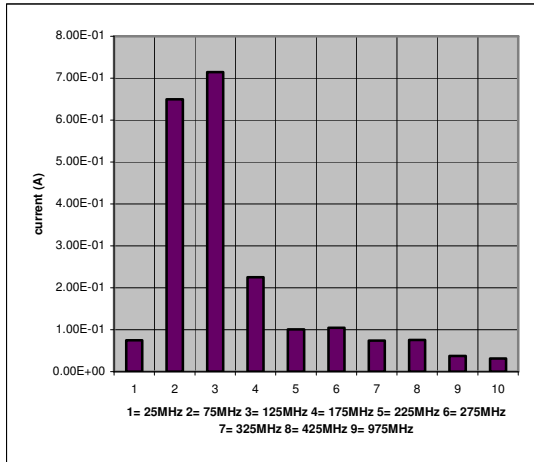


Figure 5 Cable current with a short circuit termination

Reference 1 shows data on single braid and double braid cable from 100kHz to 20GHz.

Table 2 shows the current with the transfer impedances of the cables and the transferred voltages.

Frequency (MHz)	Shield current (mA)	Transferred voltage single braid (mV)	Transferred voltage double braid (mV)
25	75		0.6
75	650	650	7.16
125	715	786	7.86
175	226	293	2.48
225	100	141	1.21
275	100	146	1.36
325	74	111	0.965
375	76	121	0.985
425	37	63	0.52
925	31	57	.47

Table 2 the value of Vt for single and double braid cables

The values in table 2 are based on well shielded cables and assume the transfer impedance of the connector and EMI backshell are very low. When these are not the case then the transferred voltages may be much higher.

Voltage developed at the input of a power line filter.

Very often the requirement for input power lines is that the lines must be unshielded. Often isolating converters are used in which case the power line and return are isolated from chassis and this isolation is also commonly a requirement. The current induced and the voltage developed due to the incident field is thus C/M.

A very good practice is to include low value capacitors between the power line and chassis and the power return and chassis at the location where the power enters the enclosure.

A good value for the capacitors is 1000pF.

Assuming 0805 surface mount 1000V capacitors connected to a double sided PCB with a single via connecting the power line side to the chassis side of the PCB the total combined capacitor parasitic inductance and via inductance is approximately 3.0nH.

Based on the short circuit current The voltage developed across a 1000pF capacitor is shown in table 3

Frequency (MHz)	Voltage across capacitor (V)
25	0.45
45	2.54
105	0.2
205	0.22
425	0.165

Table 3 voltage across 1000pF with the predicted short circuit current.

Most power line filters are designed to reduce conducted emissions and are not effective at reducing radiated emissions above a certain frequency. The main purpose for the 1000pF capacitors is to reduce the C/M current on the cable and thus the radiated emissions and this has been shown to be effective.

3 Conclusions

This article provides the predicted voltages developed into cables with an incident 200V/m E field.

An analysis of the effect on the interface circuits can then be made using a tool such as SPICE.

Alternatively a breadboard of the interfaces can be made and common laboratory equipment used to test the immunity of the circuits.

Reference1

Electromagnetic Compatibility Methods, Analysis, Circuits, and Measurement. David A. Weston. CRC press. 2017